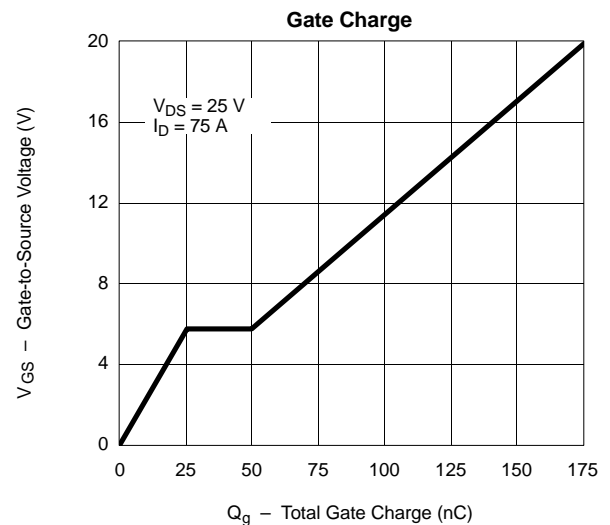
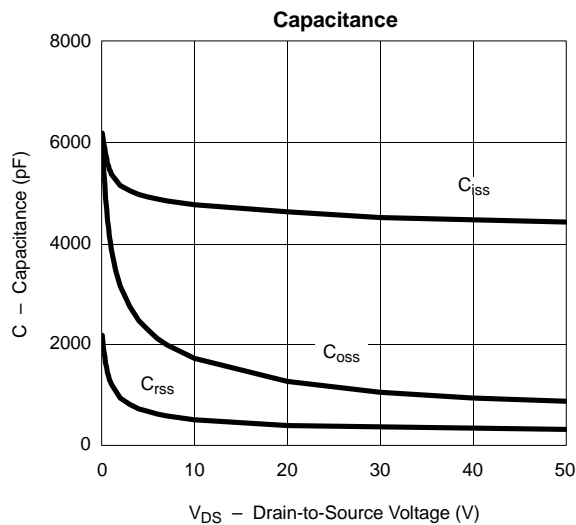
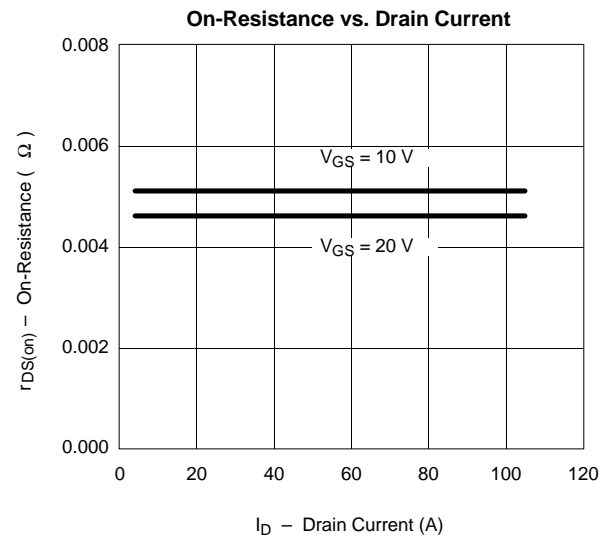
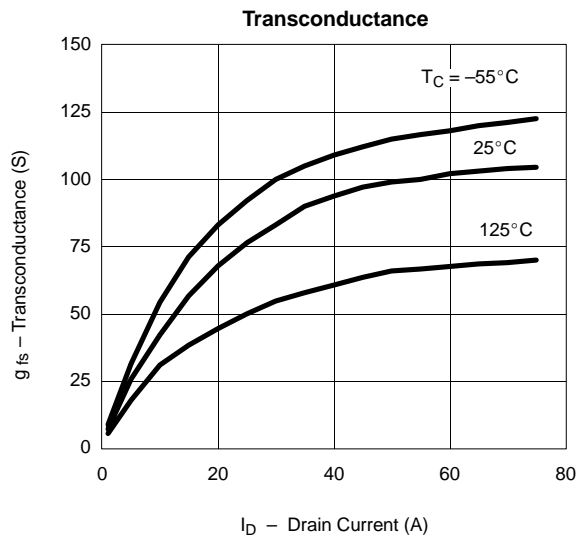
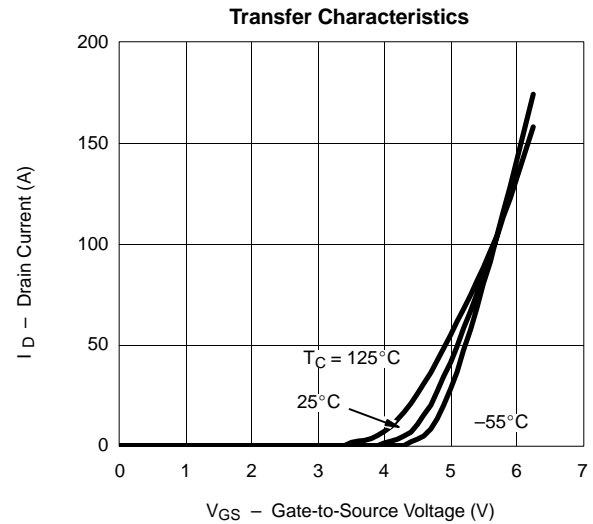
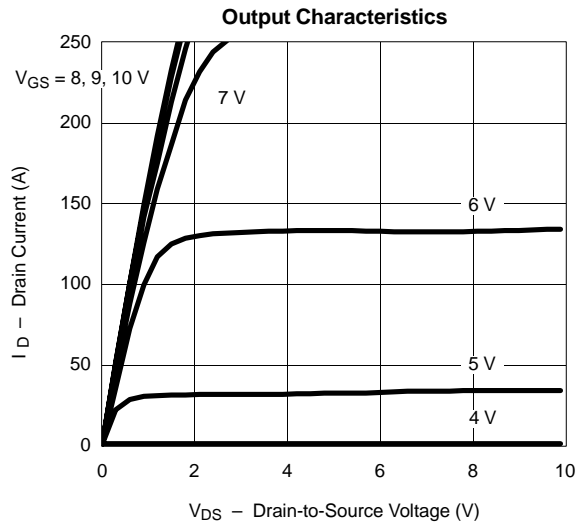
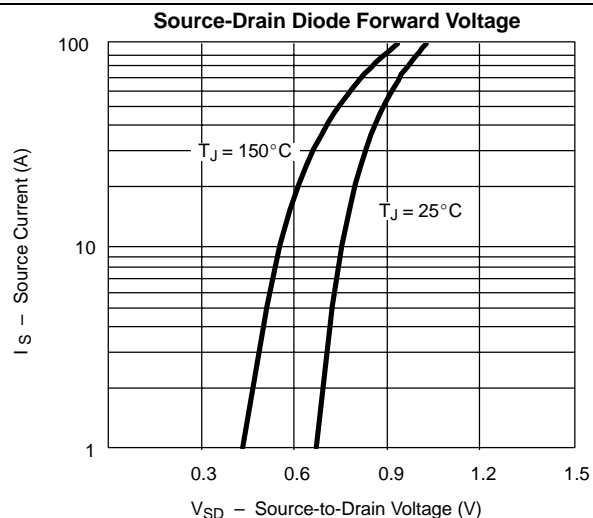
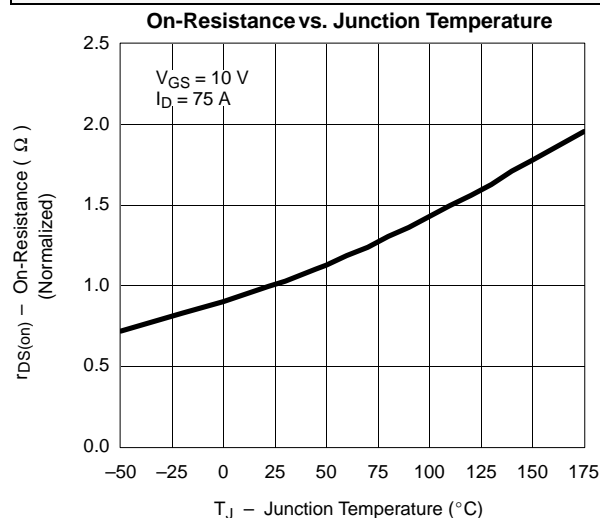
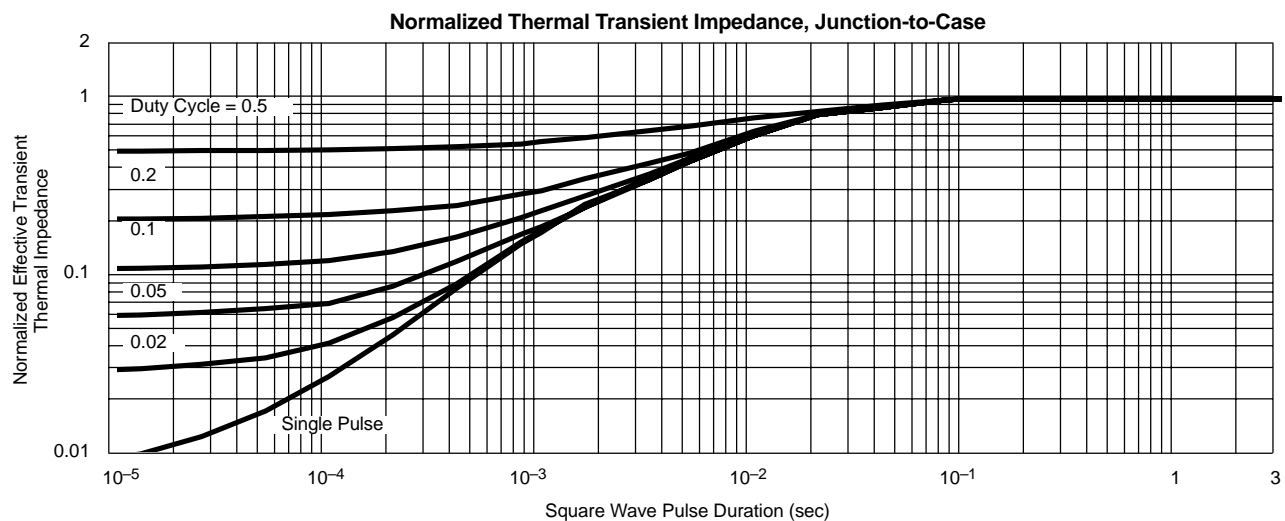
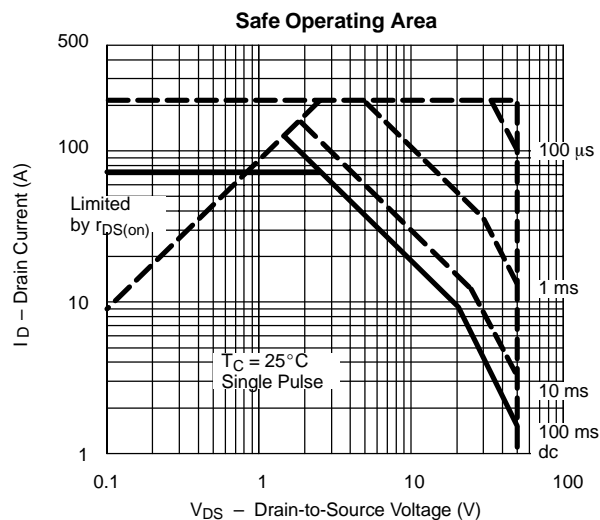
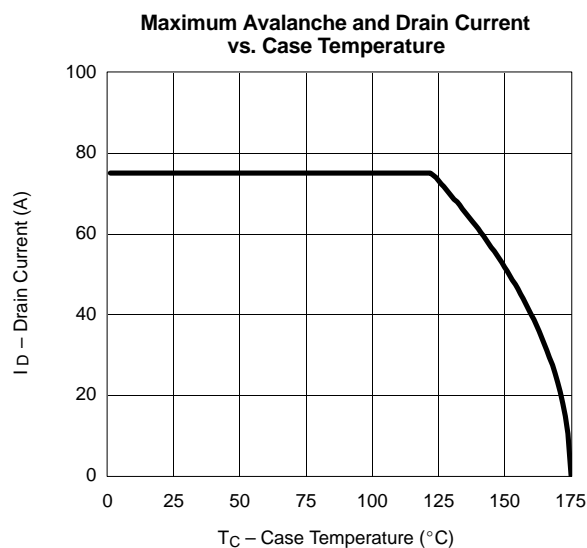


SPECIFICATIONS (T <sub>J</sub> = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA	50			V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	2.0		4.0	
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ±20 V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 0 V			1	μA
		V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125 °C			50	
		V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 175 °C			150	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 10 V	120			A
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 75 A		0.005	0.006	Ω
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 75 A, T <sub>J</sub> = 125 °C			0.010	
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 75 A, T <sub>J</sub> = 175 °C			0.012	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 60 A	30			S
Dynamic <sup>b</sup>						
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 25 V, f = 1 MHz		4500		pF
Output Capacitance	C <sub>oss</sub>			1100		
Reverse Transfer Capacitance	C <sub>rss</sub>			360		
Total Gate Charge <sup>c</sup>	Q <sub>g</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 75 A		85	120	nC
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>			25		
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			25		
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>	V <sub>DD</sub> = 25 V, R <sub>L</sub> = 0.33 Ω I <sub>D</sub> ≅ 75 A, V <sub>GEN</sub> = 10 V, R <sub>G</sub> = 2.5 Ω		20	40	ns
Rise Time <sup>c</sup>	t <sub>r</sub>			20	100	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>			50	100	
Fall Time <sup>c</sup>	t <sub>f</sub>			20	40	
Source-Drain Diode Ratings and Characteristics (T <sub>C</sub> = 25 °C) <sup>b</sup>						
Continuous Current	I <sub>S</sub>				75	A
Pulsed Current	I <sub>SM</sub>				200	
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = 75 A , V <sub>GS</sub> = 0 V		1.0	1.4	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 75 A, di/dt = 100 A/μs		65	120	ns
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>			5	8	A
Reverse Recovery Charge	Q <sub>rr</sub>			0.16	0.48	μC

## Notes

- a. Pulse test: pulse width  $\leq 300\text{ }\mu\text{sec}$ , duty cycle  $\leq 2\%$ .  
b. Guaranteed by design, not subject to production testing.  
c. Independent of operating temperature.

**TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)**

**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)****THERMAL RATINGS**



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